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## BIB DATA SHEET

CONFIRMATION NO. 3284

SERIAL NUMBER	FILING or 371(c) DATE	CLASS	GROUP ART UNIT	ATTORNEY DOCKET NO.		
10/599,035	09/18/2006	117	1792	10873.1950USWO		
<b>RULE</b>						
<b>APPLICANTS</b> Yasuo Kitaoka, Osaka, JAPAN; Yusuke Mori, Osaka, JAPAN; Takatomo Sasaki, Osaka, JAPAN; Fumio Kawamura, Osaka, JAPAN; Minoru Kawahara, Osaka, JAPAN;						
<b>** CONTINUING DATA *****</b> This application is a 371 of PCT/JP05/23798 12/26/2005						
<b>** FOREIGN APPLICATIONS *****</b> JAPAN 2004-380168 12/28/2004						
<b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 06/17/2007						
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No	35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No	<input type="checkbox"/> Met after Allowance	<b>STATE OR COUNTRY</b>	<b>SHEETS DRAWINGS</b>	<b>TOTAL CLAIMS</b>	<b>INDEPENDENT CLAIMS</b>
Verified and /FELISA CARLA HITESHEW/ Acknowledged Examiner's Signature		Initials	JAPAN	7	19	1
<b>ADDRESS</b> HAMRE, SCHUMANN, MUELLER & LARSON P.C. P.O. BOX 2902-0902 MINNEAPOLIS, MN 55402 UNITED STATES						
<b>TITLE</b> Method for Producing Silicon Carbide (Sic) Single Crystal and Silicon Carbide (Sic) Single Crystal Obtained By Such Method						
<b>FILING FEE RECEIVED</b> 900 ✓	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees			
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